IntelliMAX[™] Ultra-Small, Slew-Rate-Controlled Load Switch

FPF1203, FPF1203L, FPF1204

Description

The FPF1203 / 03L / 04 are ultra-small integrated IntelliMAX load switches with integrated P-channel switch and analog control features. Integrated slew-rate control prevents inrush current and the resulting excessive voltage drop on the power rail. The input voltage range operates from 1.2 V to 5.5 V to provide power-disconnect capability for post-regulated power rails in portable and consumer products. The low shut-off current allows power designs to meet standby and off-power drain specifications.

The FPF120x are controlled by a logic input (ON pin) compatible with standard CMOS GPIO circuitry found on Field Programmable Gate Array (FPGA) embedded processors. The FPF120x are available in 0.76 mm x 0.76 mm 4–bump WLCSP.

Features

- 1.2 V to 5.5 V Input Voltage Operating Range
- Typical R_{ON}:
 - 45 m Ω at V_{IN} = 5.5 V
 - 55 m Ω at V_{IN} = 3.3 V
 - 90 m Ω at V_{IN} = 1.8 V
 - 185 m Ω at V_{IN} = 1.2 V
- Slew Rate Control with t_R:
 - 100 μs
- Output Discharge Function on FPF1204
- Low <1.5 μA Quiescent Current
- ESD Protected: Above 7 kV HBM, 2 kV CDM
- GPIO / CMOS-Compatible Enable Circuitry
- 4-Bump, WLCSP 0.76 mm x 0.76 mm, 0.4 mm Pitch
- These are Pb-Free Devices

Applications

- Mobile Devices and Smart Phones
- Portable Media Devices
- Tablet PCs
- Advanced Notebook, UMPC, MID
- Portable Medical Devices
- GPS and Navigation Equipment



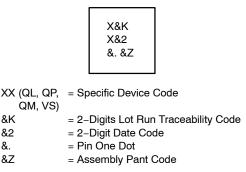
ON Semiconductor®

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WLCSP4 0.76x0.76x0.586 CASE 567SS

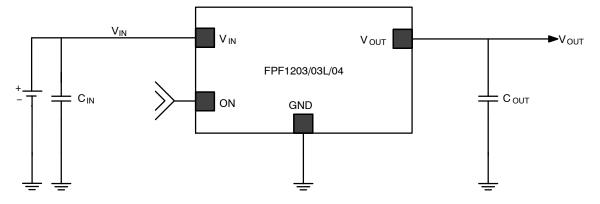
MARKING DIAGRAM



ORDERING INFORMATION

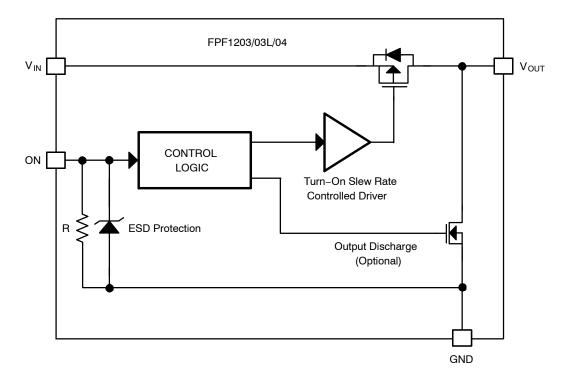
See detailed ordering and shipping information on page 8 of this data sheet.

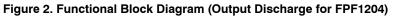
APPLICATION DIAGRAM





FUNCTIONAL BLOCK DIAGRAM





PIN CONFIGURATIONS





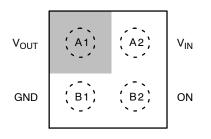


Figure 5. Pin Assignments (Top View)

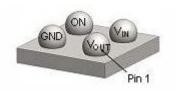


Figure 4. WLCSP Bumps Facing Up (Bottom View)

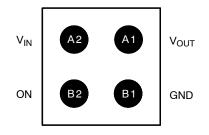


Figure 6. Pin Assignments (Bottom View)

PIN DEFINITONS

Pin No.	Name	Description
A1	V _{OUT}	Switch output
A2	V _{IN}	Supply input: input to the power switch
B1	GND	Ground
B2	ON	ON/OFF Control, active HIGH; FPF1203/04
B2	ON	ON/OFF Control, active LOW; FPF1203L

ABSOLUTE MAXIMUM RATINGS

Symbol	Parame	eter	Min	Max	Unit
V _{IN}	V _{IN} , V _{OUT} , V _{ON} to GND	-0.3	6.0	V	
I _{SW}	Maximum Continuous Switch Current at Ambier	-	2.2	А	
PD	Power Dissipation at $T_A = 25^{\circ}C$	-	1.0	W	
T _{STG}	Storage Temperature Range	-65	+150	°C	
Θ_{JA}	nermal Resistance, Junction-to-Ambient 1S2P with One Thermal Via (Note 1)		-	110	°C/W
	1S2P without Thermal Via (Note 2)		-	95	
ESD	Electrostatic Discharge Capability (Note 1, 2)	Electrostatic Discharge Capability (Note 1, 2) Human Body Model, JESD22-A114		-	kV
		Charged Device Model, JESD22-C101	2	-	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured using 2S2P JEDEC std. PCB.

2. Measured using 2S2P JEDEC PCB COLD PLATE Method.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Мах	Unit
V _{IN}	Input Voltage	1.2	5.5	V
T _A	Ambient Operating Temperature	-40	+85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $V_{IN} = 1.2$ V to 5.5 V and $T_A = -40$ to $+85^{\circ}$ C. Typical values are at $V_{IN} = 3.3$ V and $T_A = 25^{\circ}$ C.)

Symbol	Parameter		Condition	Min	Тур	Max	Unit
BASIC OPE	RATION						
V _{IN}	Supply Voltage			1.2	-	5.5	V
I _{Q(OFF)}	Off Supply Current	FPF1203/04	V_{ON} = GND, V_{OUT} = Open, V_{IN} = 5.5 V	-	0.1	1.0	μA
	FPF1203L		$V_{ON} = V_{IN}, V_{OUT} = Open, V_{IN} = 5.5 V$	-	1.0	2.0	
I _{SD}	Shutdown Current	FPF1203/04	V _{ON} = GND, V _{OUT} = GND	-	– 0.1 1.0 μ		μA
		FPF1203L	V _{ON} = V _{IN} , V _{OUT} = GND	-	1.2	3.0	
l _Q	Quiescent Current	FPF1203/04	$I_{OUT} = 0 \text{ mA}, V_{ON} = V_{IN}, = 5.5 \text{ V}$	-	0.1	1.5	μΑ
		FPF1203L	$I_{OUT} = 0$ mA, $V_{ON} = GND$, $V_{IN} = 5.5$ V				
R _{ON}	On Resistance		V_{IN} = 5.5 V, I_{OUT} = 200 mA, T_A = 25°C	-	45	55 (Note 3)	mΩ
			V_{IN} = 3.3 V, I_{OUT} = 200 mA, T_A = 25°C	-	55	65 (Note 3)	
			V_{IN} = 1.8 V, I_{OUT} = 200 mA, T_A = 25°C	_	90	100 (Note 3)	
			V_{IN} = 1.2 V, I_{OUT} = 200 mA, T_A = 25°C	_	185	220 (Note 3)	
			V_{IN} = 1.8 V, I_{OUT} = 200 mA, T_A = 85°C (Note 3)	_	-	105	
R _{PD}	Output Discharge R _{PULL DOWN}		V_{IN} = 3.3 V, V_{ON} = OFF, I_{FORCE} = 20 mA, T_A = 25°C, FPF1204	-	65	75	Ω
V _{IH}	On Input Logic HIGH	I Voltage	V _{IN} = 1.2 V to 5.5 V	1.15	-	-	V
V _{IL}	On Input Logic LOW	Voltage	V _{IN} = 1.2 V to 5.5 V	-	-	0.65	V
R _{ON_PD}	Pull-Down Resistan	ce at ON Pin	V _{IN} = 1.2 V to 5.5 V	-	8.3	-	MΩ
I _{ON}	On Input Leakage		V _{ON} = V _{IN} or GND	-	-	1	μA
OYNAMIC C	HARACTERISTICS		•				
t _{DON}	Turn-On Delay (Not	e 4)	$V_{IN} = 3.3 \text{ V}, \text{ R}_{L} = 10 \Omega, \text{ C}_{L} = 0.1 \mu\text{F},$	-	70	-	μs
t _R	V _{OUT} Rise Time (No	te 4)	T _A = 25°C, FPF1204	-	100	-	
t _{ON}	Turn-On Time (Note	6)	1	-	170	-	
t _{DOFF}	Turn-Off Delay (Not	e 4, 5)	V _{IN} = 3.3 V, R _L = 10 Ω, C _L = 0.1 μF,	_	0.5	-	μs
t _F	V _{OUT} Fall Time (Not	e 4, 5)	T _A = 25°C, FPF1203L	-	2.0	-	
t _{OFF}	Turn–Off Time (Note 5, 7)			-	2.5	-	
t _{DOFF}	Turn-Off Delay (Note 4, 5)		$V_{IN} = 3.3 \text{ V}, \text{ R}_{L} = 500 \Omega, \text{ C}_{L} = 0.1 \mu\text{F},$	-	6	-	μs
t _F	V _{OUT} Fall Time (Note 4, 5)		$T_A = 25^{\circ}C$, FPF1203L	-	115	-	
t _{OFF}	Turn-Off Time (Note	5, 7)	1	-	121	-	
t _{DOFF}	Turn-Off Delay (Not	e 4, 5)	$V_{IN} = 3.3 \text{ V}, \text{ R}_{L} = 10 \Omega, \text{ C}_{L} = 0.1 \mu\text{F},$	-	4.0	-	μs
t _F	V _{OUT} Fall Time (Not	e 4, 5)	T _A = 25°C, FPF1203	_	2.9	-	
t _{OFF}	Turn-Off Time (Note	5, 7)	1	_	7.3	_	

ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $V_{IN} = 1.2$ V to 5.5 V and $T_A = -40$ to +85°C. Typical values are at V_{IN} = 3.3 V and $T_A = 25^{\circ}C.$) (continued)

Symbol	Parameter	ameter Condition		Тур	Max	Unit				
DYNAMIC C	DYNAMIC CHARACTERISTICS									
tDOFF	Turn-Off Delay (Note 4, 5)	$V_{IN} = 3.3 \text{ V}, \text{ R}_{L} = 500 \Omega, \text{ C}_{L} = 0.1 \mu\text{F},$	-	6	-	μs				
t _F	V _{OUT} Fall Time (Note 4, 5)	T _A = 25°C, FPF1203	-	115	-					
t _{OFF}	Turn-Off Time (Note 5, 7)		-	121	-					
t _{DOFF}	Turn-Off Delay (Note 4, 5)	$V_{IN} = 3.3 \text{ V}, \text{ R}_{L} = 10 \Omega, \text{ C}_{L} = 0.1 \mu\text{F},$	-	4.0	-	μs				
t _F	V _{OUT} Fall Time (Note 4, 5)	T _A = 25°C, FPF1204 (Note 5)	-	2.5	-					
t _{OFF}	Turn–Off Time (Note 5, 7)		-	6.5	-					
t _{DOFF}	Turn-Off Delay (Note 4, 5)	$V_{IN} = 3.3 \text{ V}, \text{ R}_{L} = 500 \Omega, \text{ C}_{L} = 0.1 \mu\text{F},$	-	6	-	μs				
t _F	V _{OUT} Fall Time (Note 4, 5)	T _A = 25°C, FPF1204 (Note 5)	-	11	-					
t _{OFF}	Turn-Off Time (Note 5, 7)		_	17	_					

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. This parameter is guaranteed by design and characterization; not production tested.

4. $t_{DON}/t_{DOFF}/t_R/t_F$ are defined in Figure 23. 5. Output discharge enabled during off-state.

6. $t_{ON} = t_R + t_{DON}$ 7. $t_{OFF} = t_F + t_{DOFF}$

TYPICAL PERFORMANCE CHARACTERISTICS

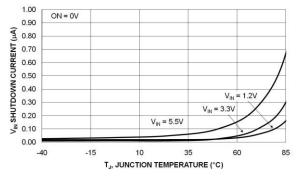
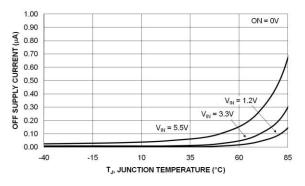


Figure 7. Shutdown Current vs. Temperature





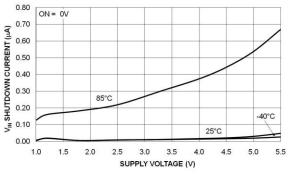
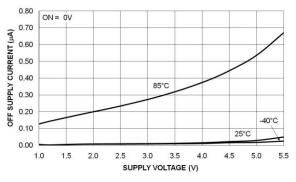


Figure 8. Shutdown Current vs. Supply Voltage





TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

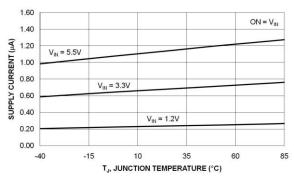
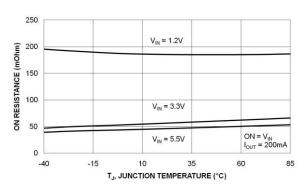
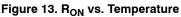


Figure 11. Quiescent Current vs. Temperature





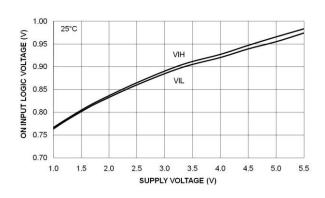


Figure 15. ON Pin Threshold vs. V_{IN}

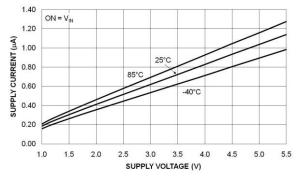


Figure 12. Quiescent Current vs. Supply Voltage

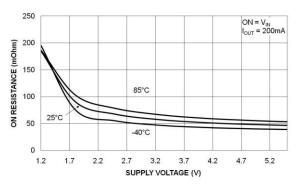


Figure 14. R_{ON} vs. Supply Voltage

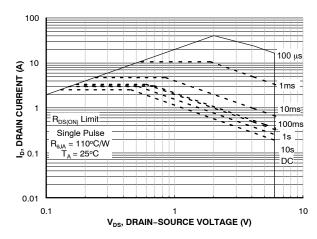


Figure 16. Drain Current vs. Drain–Source Voltage Safe Operating Area

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

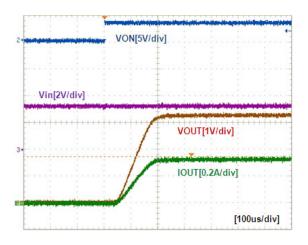


Figure 17. Turn–On Response – FPF1203 / 04 (V_{IN} = 3.3 V, C_{IN} = 1 μ F, C_{OUT} = 0.1 μ F, R_L = 10 Ω)

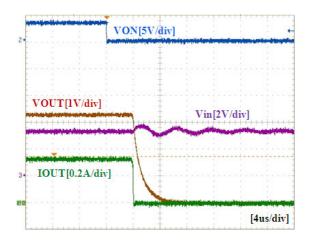
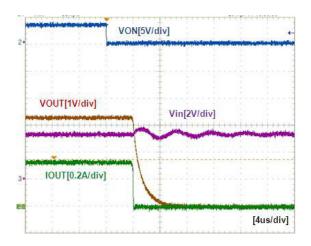
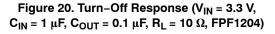


Figure 18. Turn–Off Response – FPF1203 (VIN = 3.3 V, CIN = 1 $\mu\text{F},$ COUT = 0.1 $\mu\text{F},$ RL = 10 Ω)





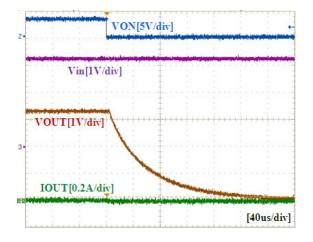


Figure 19. Turn–Off Response – FPF1203 (V_IN = 3.3 V, C_IN = 1 $\mu\text{F},$ C_OUT = 0.1 $\mu\text{F},$ RL = 500 $\Omega)$

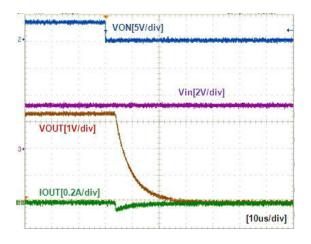


Figure 21. Turn–Off Response (V_{IN} = 3.3 V, C_{IN} = 1 μ F, C_{OUT} = 0.1 μ F, R_L = 500 Ω , FPF1204)

OPERATION AND APPLICATION DESCRIPTION

The FPF1203 / 03L / 04 are low-R_{ON} P-channel load switches with controlled turn-on. The core of each device is a 55 m Ω P-channel MOSFET and controller capable of functioning over a wide input operating range of 1.2 to 5.5 V.

The FPF1204 contain a 65 Ω on-chip load resistor for quick output discharge when the switch is turned off.

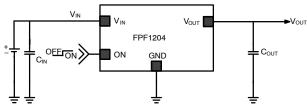


Figure 22. Typical Application

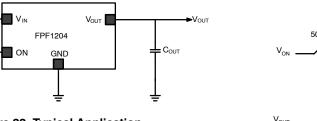
Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor or short-circuit, a capacitor must be placed between the V_{IN} and GND pins. A 1 μ F ceramic capacitor, CIN, placed close to the pins is usually sufficient. Higher-value CIN can be used to reduce the voltage drop in higher-current applications.

Output Capacitor

ORDERING INFORMATION

A 0.1 µF capacitor, C_{OUT}, should be placed between the V_{OUT} and GND pins. This capacitor prevents parasitic board inductance from forcing VOUT below GND when the switch is on. C_{IN} greater than C_{OUT} is highly recommended.





 C_{OUT} greater than C_{IN} can cause V_{OUT} to exceed V_{IN} when

the system supply is removed. This could result in current

3.3 V

50

flow through the body diode from V_{OUT} to V_{IN}.

Board Layout

For best performance, traces should be as short as possible. To be most effective, input and output capacitors should be placed close to the device to minimize the effect of parasitic trace inductance on normal and short-circuit operation. Using wide traces or large copper planes for all pins (VIN, VOUT, ON, and GND) minimizes the parasitic electrical effects and the case-ambient thermal impedance. However, the VOUT pin should not connect directly to the battery source due to the discharge mechanism of the load switch.

Part Number	Top Mark	Switch (Typical) at 3.3V _{IN}	Output Discharge	ON Pin Activity	t _R	Package	Shipping [†]
FPF1203UCX	QL	55 m Ω	NA	Active HIGH	100 μs	4-Bump, Wafer-Level	3000 / Tape & Reel
FPF1203LUCX	QP	$55~\mathrm{m}\Omega$	NA	Active LOW	100 μs	Chip-Scale Package (WLCSP), 0.76 mm x	3000 / Tape & Reel
FPF1204UCX	QM	55 m Ω	65 Ω	Active HIGH	100 μs	0.76 mm, 0.4 mm Pitch	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

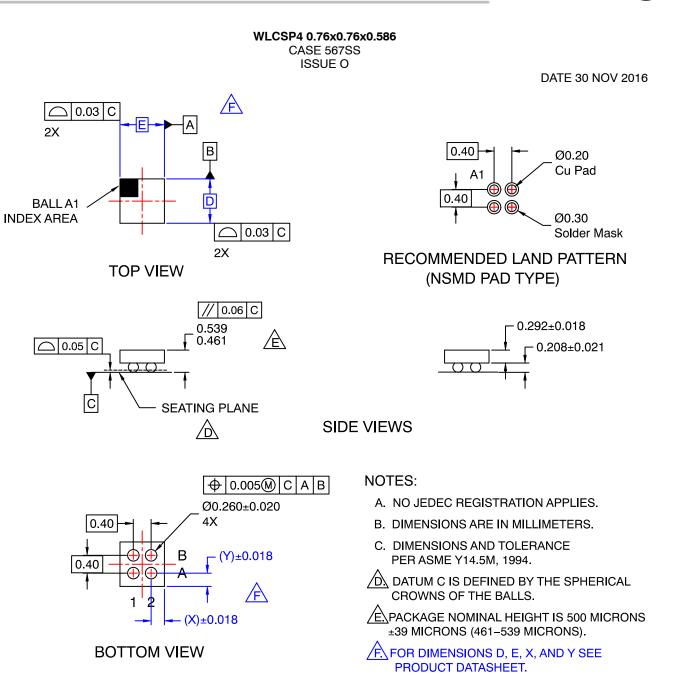
The table below pertains to the Packaging information on the following page.

PRODUCT DIMENSIONS

D E		Х	Y	
760 μm ±30 μm	760 μm ±30 μm	0.180 mm \pm 0.018 μ m	0.180 mm ±0.018 μm	

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